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Chemical transformations at the nanoscale: nanocrystal-seeded synthesis of β - $\text{Cu}_2\text{V}_2\text{O}_7$ with enhanced photoconversion efficiencies†

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Nanocrystal-seeded synthesis relies on the reaction of nanocrystal seeds with a molecular precursor and it can be regarded as the link between sol–gel and solid-state chemistries. This synthesis approach aims at accessing compositionally complex materials, yet to date its full potential remains unexploited. Herein, surface oxidized Cu nanocrystal seeds with diameters from 6 nm to 70 nm are reacted with vanadium acetylacetonate to form β - $\text{Cu}_2\text{V}_2\text{O}_7$ with a tunable grain size ranging from 29 nm to 63 nm. *In situ* X-ray diffraction measurements evidence the occurrence of a solid-state reaction between the NC seeds and the vanadium oxide formed during the annealing. The variation of the ion diffusion lengths, the homogeneity of the precursor solution and the number of nucleation sites with the NC seed size explains the lower formation temperature, the smaller grain size and the higher grain size monodispersity of β - $\text{Cu}_2\text{V}_2\text{O}_7$ as the seed size decreases. Finally, the tunability afforded by the nanocrystal-seeded synthesis provides a unique opportunity to correlate the photoelectrochemical performance with the grain size in a size regime close to the charge carrier diffusion length of β - $\text{Cu}_2\text{V}_2\text{O}_7$ (20–40 nm). The net photocurrent density peaks when the grain size is 39 nm by reaching 0.23 mA cm^{-2} at 1.23 V vs. RHE in the presence of a hole scavenger. While still far from the theoretical limit, this result overcomes the current state-of-the-art for β - $\text{Cu}_2\text{V}_2\text{O}_7$. An interesting double fold increase in the photocurrent is found in mixed phase β - $\text{Cu}_2\text{V}_2\text{O}_7/\text{CuV}_2\text{O}_6$ samples, suggesting that nanostructuring and heterostructuring are beneficial to the performance.

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Introduction

Multinary metal oxides are emerging as key materials to advance diverse applications ranging from batteries to flexible electronics, catalysis and plasmonics.^{1–12} Achieving control over crystalline phases, stoichiometry, grain size and morphology is of the uttermost importance considering the correlation of these structural features with the physical–chemical properties and with the device performance. This urgent need requires novel synthetic approaches, which include various seeding strategies, photochemical synthesis and nanoscale solid-state reactions.^{1–13} To cite one example, Bretos *et al.* introduced crystalline PbTiO_3 nanoseeds in a sol–gel mixture of molecular

precursors to successfully reduce the crystallization temperature of $\text{Pb}(\text{Zr}_{0.52}\text{Ti}_{0.48})\text{O}_3$, thus enabling its integration on flexible substrates.⁵ As a second example, the development of a photochemical metal–organic deposition has given access to an amorphous mixed metal oxide with excellent catalytic properties for oxygen evolution.³ Another example comes from Chuang *et al.* who have exploited the nanoscale solid state reaction between ZnO and GaN nanocrystals to tune the composition and the band gap of $(\text{Ga}_{1-x}\text{Zn}_x)(\text{N}_{1-x}\text{O}_x)$, a material with intriguing optical properties relevant for solar fuel generation.^{9–12} Finally, our group has recently developed a nanocrystal-seeded growth approach wherein $\text{Bi}_x\text{Sb}_{1-x}$ nanocrystalline thin films react with vanadium precursor to afford a new photoanode material, $\text{BiV}_{1-x}\text{Sb}_x\text{O}_4$.¹³ This compound had been predicted by theoretical calculations but attempts to synthesize it by more conventional approaches, such as sol–gel, solid-state synthesis and spray pyrolysis, had been unsuccessful.

Copper vanadates have been recently highlighted as promising photoanode materials for tandem photoelectrochemical devices.¹⁴ There are 26 phases of copper vanadate listed in the Inorganic Crystal Structure database with different structural and opto-electronic properties. Various techniques like solid state synthesis,^{15,16} solution approaches,^{17–20} physical vapor

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† Electronic supplementary information (ESI) available: Details of the Cu NC synthesis procedure, ligand stripping procedure, sample preparation methods, and experimental details for SEM, TEM, TGA, Raman spectroscopy, *in situ* and *ex situ* XRD, UV-Vis spectroscopy, FTIR spectroscopy and PEC measurements. See DOI: 10.1039/c8sc01314d



deposition,^{21–23} electrospraying,²⁴ sol–gel methods²⁵ have been applied to access different crystalline phases within this family of compounds.

Several stoichiometries of copper vanadates have been obtained by varying the synthesis parameters such as the precursor ratio and the annealing temperature. The reported band gaps are in the range 1.8–2.1 eV, suggesting the possibility to reach maximum photocurrent densities up to 13 mA cm^{−2}. Nevertheless, the values reported so far for different copper vanadates in the presence of a hole scavenger are usually below 0.1 mA cm^{−2}, thus much lower than this theoretical limit.^{17–23} In previous studies, the high annealing temperatures above 450 °C have resulted in grain sizes varying from 200 nm to 1 μm.^{17–25} These grain sizes are much larger than the charge carrier diffusion length (20–40 nm), which may be among the causes for the low photocurrent density in these studies.²² Thus, synthesizing copper vanadates with monodisperse grain sizes ≤40 nm is expected to improve the photoconversion efficiency of this promising material. More importantly, tuning the grain size in this range will lead towards a more fundamental understanding of the intimate relationship between grain size and performance. Electrodeposition has been demonstrated to be a very powerful technique to access nanoporous ternary metal oxide photoelectrodes, yet the grain size monodispersity and tunability are still limited.^{20,26,27} Therefore, expanding the available methods to synthesize multication oxides is highly desirable if one aims at correlating morphological parameters with performance metrics.

Experimental

Materials

Copper(i) acetate (CuOAc, 97%) and hexane (anhydrous, 95%) were purchased from TCI Deutschland GmbH. Vanadium(v) oxide (V₂O₅, 99.9%), toluene (anhydrous), dimethylformamide (DMF, anhydrous), acetonitrile (ACN, anhydrous), and vanadium(iii) chloride (VCl₃, 99%) were purchased from abcr GmbH. Trioctylamine (TOA, 98%), oleylamine (OLAM, 70%), tetradecylphosphonic acid (TDPA, 97%), trimethyloxonium tetrafluoroborate (Me₃OBF₄, 95%), ethanol (anhydrous), trioctylphosphine (TOP, 90%), copper(i) chloride (CuCl, 99.99%), copper(ii) oxide (CuO, 98%), and copper(ii) nitrate hydrate (Cu(NO₃)₂·H₂O, 99.999%) were purchased from Sigma-Aldrich and used as received. Ethylene glycol (99.5%) was purchased from Roth AG.

Synthesis of the copper nanocrystal (Cu NC) seeds

The different sizes of the copper nanocrystal seeds were obtained by modifying two procedures reported in the literature.^{28,29} Details are reported in the ESI.†

Ligand stripping

The native ligands were removed by following Rosen *et al.*³⁰ First of all, the concentration of the nanocrystal solutions was determined by thermogravimetric analysis. Then, 1 mL of a 0.05 M solution of the as-synthesized Cu NCs in hexane was

added to a solution of 50 mg of Me₃OBF₄ in 1 mL of ACN and vigorously stirred for 3 minutes in a glovebox. 1 mL of toluene was added to the solution followed by centrifugation at 6000 rpm for 15 minutes. The precipitate was dispersed in 250 μL of DMF. The same procedure was followed for all the sizes of the Cu NCs.

NC-seeded synthesis of copper vanadate

3 μmol of ligand-stripped Cu NCs in DMF (60 μL of a 0.05 M solution) were surface-oxidized in a vial by flowing O₂ for 15 min to form Cu@Cu₂O core@shell NCs, as reported by Hung *et al.*²⁸ 3 μmol of VO(acac)₂ in DMF (60 μL of a 0.05 M stock solution) were mixed with the surface oxidized Cu NCs. The as-obtained precursor solution (120 μL) was drop cast on 1.5 cm × 1.5 cm substrates (silicon, quartz and FTO for structural, optical and photoelectrochemical characterization, respectively) on a hot plate at 60 °C in a glovebox. Annealing was performed in air in a tube furnace at 350 °C for 8 hours, preceded by an 8 °C min^{−1} heating ramp, followed by natural cooling.

Sol-gel synthesis of copper vanadate

The sol-gel samples were prepared from Cu(NO₃)₂ and VCl₃, according to the method reported by Guo *et al.*¹⁸ One 0.05 M stock solution of Cu(NO₃)₂ in ethylene glycol and one 0.05 M stock solution of VCl₃ in ethylene glycol were prepared. 60 μL of each were mixed by sonication for 10 minutes. The obtained 120 μL of precursor solution were drop-cast on one 1.5 × 1.5 cm silicon substrate placed on a hot plate at 180 °C. Annealing was carried out in air in a tube furnace by heating at 350 °C with an 8 °C min^{−1} ramp followed by soaking for 8 hours.

Solid-state synthesis of copper vanadate

CuO and V₂O₅ powders were co-ground in an agate mortar and annealed in a ceramic pan in a tube furnace at 500 °C which was reached with a heating ramp of 8 °C min^{−1}.

In situ X-ray diffraction

The measurements were performed in a custom-made heating cell implemented using a Bruker D8 Discover diffractometer. The maximum time resolution for our experiments was 10 minutes. More details are provided in the ESI.†

Results and discussion

Herein, we describe a novel approach to synthesize nanostructured β-Cu₂V₂O₇ thin films with tunable grain sizes below 100 nm, based on the reaction of Cu nanocrystals (NCs) of different sizes with a vanadium molecular precursor.

This approach is referred to as nanocrystal-seeded synthesis and it builds upon our previous work.¹³ We find that the size of the NC seeds in the precursor solution plays a key role in controlling the phase composition and the grain size of the final reaction product. Monodisperse Cu NC seeds with diameters ranging between 6 nm and 70 nm were synthesized using colloidal chemistry, stripped of the native organic ligands and



surface oxidized with a controlled oxygen flow. The as-obtained Cu@Cu₂O NCs were then mixed with the molecular vanadium precursor (vanadyl acetylacetonate, VO(acac)₂) to form a 1 : 1 molar ratio solution in dimethylformamide (DMF). The removal of the native ligands is a key step to obtain a homogeneous solution of the vanadium precursor and the NCs, which are otherwise soluble only in organic apolar solvents. The resulting mixtures were dropcasted onto different substrates and annealed at 350 °C in air for 8 hours. The whole process is sketched in Fig. 1. These reaction conditions were chosen to synthesize high purity nanocrystalline β-Cu₂V₂O₇ films. The temperature of 350 °C was the lowest temperature to form crystalline products. Higher annealing temperatures resulted in larger grain sizes (>150 nm) and in major phase segregation of V₂O₅ and CuV₂O₆ (Fig. S1†). A 1 : 1 molar ratio between the Cu seeds and VO(acac)₂ was set to minimize the presence of CuO and V₂O₅ as secondary phases (Fig. S2†).

Fig. 2A–F show the transmission electron microscopy (TEM) images of the Cu NC seeds with increasing average diameter from 6 nm to 70 nm. Fig. 2G–L show the top-view scanning electron microscopy (SEM) images of the films obtained upon reaction of these seeds with the vanadium precursor. The films consist of a continuous network of nanoscale grains. While accurate measurements are hindered by the resolution limit of the SEM, a qualitative increase of the grain size and of the polydispersity of the same is observed as the size of the seeds increases. Cross-sectional SEM (Fig. S3†) demonstrates the high porosity of these films compared to recently studied compact films.^{21,22}

The structural and compositional characterization of the films was performed by XRD and Raman spectroscopy (Fig. 3 and S4†). Next to the complexity of the CuO–V₂O₅ phase diagram itself,^{17–25} the XRD data analysis was complicated by a number of factors, such as the close similarity of the lattice parameters of different phases and the resulting peak overlap, the significant line broadening associated with grain sizes smaller than 100 nm and the potential preferred orientation of the grains on the substrate. Quantitative Rietveld refinement was performed to analyze the phase composition of the synthesized samples (Table S1 and Fig. S5†). The main crystalline phase in all samples is monoclinic β-Cu₂V₂O₇ whose representative signals are the Bragg peak at 2θ = 24.7° and the triplet at 2θ = 28.1°, 28.8° and 29.1°. The peak at 2θ = 26.1° was attributed to V₂O₅, which is found in all the samples as an impurity phase (<10%). In the films synthesized from Cu NC seeds of 60 and 70 nm in size, the triclinic CuV₂O₆ crystallizes as an additional minor phase (around 20%) manifested by the peaks at 2θ = 27° and 29.3°. The diffraction line broadening due

to size effects was quantified using XRD data to extract the grain size of β-Cu₂V₂O₇ (Table S1†). The grain size systematically increases from 29 nm to 63 nm upon increasing the Cu NC seed size from 6 nm to 70 nm. Raman spectroscopy was utilized to support the XRD results (Fig. S4†).

To get insights into the chemical conversion mechanism, *in situ* XRD studies were carried out using a home-built cell (Fig. 4 and S6†). The initial scan from films obtained by depositing the solution of 6 nm Cu@Cu₂O and VO(acac)₂ (Fig. 4A, pattern a) shows the unreacted vanadium precursor and the very broad peaks corresponding to the NC seeds. The presence of the pure copper core was confirmed by ex-situ measurements (Fig. S7†), as in the used high temperature cell the Cu reflections are obscured by the strong signal from the heating strip. Furthermore, the strong Cu-reflections lie outside the 2 Theta range plotted in Fig. 4A. Upon temperature increase and solvent evaporation, an amorphous VO_x matrix is formed and the NC seeds are nested within it (Fig. 4A, pattern b). At around 300 °C, the seeds oxidize further to CuO, and in the same scan the ziesite phase β-Cu₂V₂O₇ is detected (Fig. 4A, pattern c). At 350 °C β-Cu₂V₂O₇ constitutes the major phase in the XRD pattern (Fig. 4A, pattern d). Though no diffraction peaks could be assigned to vanadium oxide, V₂O₅ does form at around 300 °C if the vanadium precursor is deposited on the substrate alone and it is subjected to the same thermal treatment (Fig. S6†). The fact that vanadium oxide is not observed during the conversion process may be due to the modification of its nucleation and growth kinetics when the reaction occurs in the confined spaces between the NC seeds. Alternatively, its rapid consumption during the formation of the ternary phase may be outside the time resolution of the *in situ* experiments. This hypothesis suggests that the formation of the ternary phases is likely to proceed *via* a solid state reaction between the CuO NCs and the amorphous VO_x matrix (or V₂O₅ crystals, if indeed crystalline vanadium forms and reacts on a timescale below the sampling time resolution, which is 10 minutes). An overview of the conversion mechanism is sketched in Fig. 4B.

In solid-state synthesis, the number of grain contacts (nucleation sites), the surface reaction rate and the ion diffusion rate control the conversion kinetics of the solid precursors into the final product. If we refer to homogeneity as the degree of intermixing of the two precursors, higher homogeneity will facilitate the conversion by providing more nucleation sites.² The shorter diffusion lengths and higher homogeneity accompanying the smaller sizes of the precursors are expected to result in lower reaction temperatures and/or shorter reaction times, as well as in a more uniform composition and morphology of the final product. The smallest precursor size is

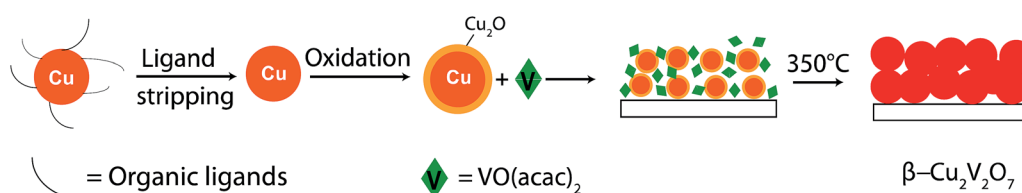


Fig. 1 Schematic representation of the chemical conversion of Cu NC seeds into β-Cu₂V₂O₇.



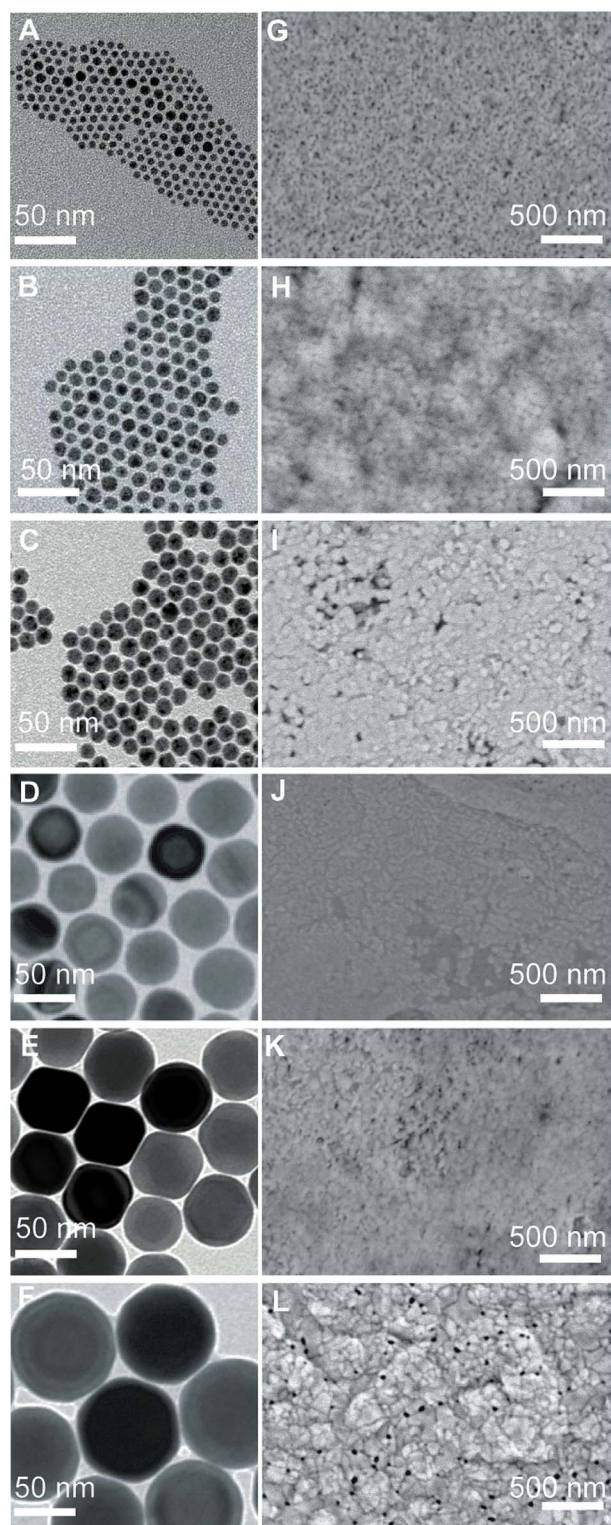


Fig. 2 (A–F) TEM images of Cu NCs with an average diameter of 6 nm, 11 nm, 14 nm, 40 nm, 60 nm and 70 nm respectively. (G–L) Top-view SEM images of the thin films synthesized from Cu NCs of 6 nm, 11 nm, 14 nm, 40 nm, 60 nm and 70 nm, respectively.

one molecule, and thus sol–gel reactions should allow for the lowest reaction temperature at which the final product can crystallize. The NC-seeded synthesis can be regarded as the link

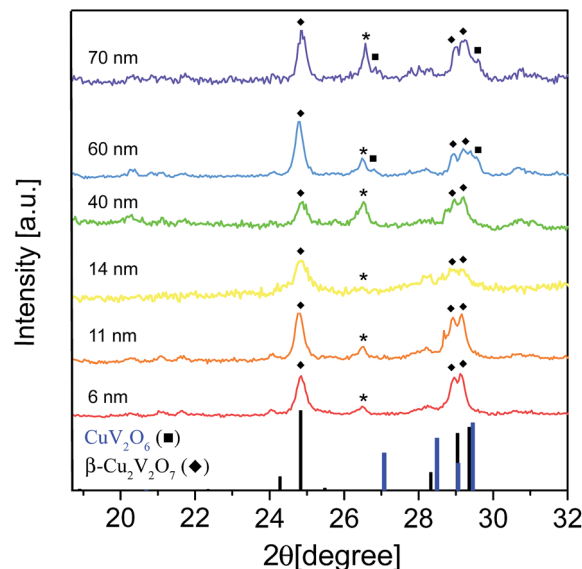


Fig. 3 XRD patterns of films synthesized from Cu NC seeds of 6 nm, 11 nm, 14 nm, 40 nm, 60 nm and 70 nm, reacted with $\text{VO}(\text{acac})_3$ and annealed at 350 °C for 8 hours. Monoclinic $\beta\text{-Cu}_2\text{V}_2\text{O}_7$ (PDF-01-076-2820) and triclinic CuV_2O_6 (PDF-00-045-1054) reference positions of the Bragg peaks are reported at the bottom. The asterisk symbol * indicates the peaks for V_2O_5 (PDF-00-041-1426).

between sol–gel and solid state reactions (Fig. 4C). The fine tunability of the colloidal NC seeds provided us with a unique opportunity to explore the impact of the precursor size in the intermediate nanoscale regime between the sol–gel process and the solid-state reaction between bulk powders.

We compared the nanocrystal-seeded synthesis, the sol–gel reaction between Cu and V molecular precursors ($\text{Cu}(\text{NO}_3)_2 \cdot \text{H}_2\text{O}$ and VCl_3) and the solid state reaction between CuO and V_2O_5 bulk powders. In all these experiments the Cu : V molar ratio was kept 1 : 1. Fig. 4D provides a summary of the obtained results while details and *in situ* diffraction data are reported in the ESI (Fig. S6†). In the sol–gel approach, the temperature at which $\beta\text{-Cu}_2\text{V}_2\text{O}_7$ was detected ($T_{\text{in situ}}$) was 200 °C. The 11 nm, 14 nm and 40 nm NC seeds followed the same conversion kinetics as the 6 nm seeds and thus $T_{\text{in situ}} = 300$ °C. For the 60 nm and 70 nm seeds, the biphasic product $\beta\text{-Cu}_2\text{V}_2\text{O}_7 + \text{CuV}_2\text{O}_6$ was detected at 350 °C. In the case of bulk powders, $\beta\text{-Cu}_2\text{V}_2\text{O}_7 + \text{CuV}_2\text{O}_6$ was formed at 500 °C. Interestingly, $\beta\text{-Cu}_2\text{V}_2\text{O}_7 + \text{CuO}$ was measured when 6 nm Cu NCs were used instead of $\text{Cu}@\text{Cu}_2\text{O}$ NCs (Fig. S8†). We found that purely metallic Cu NCs sinter to a size above 100 nm during annealing. The larger grain size might then require differently optimized conditions to fully convert the CuO . In fact, the literature reports that micrometer sized CuO fibers convert to $\text{Cu}_{11}\text{V}_6\text{O}_{26}$ upon reaction with $\text{VO}(\text{acac})_3$ at 600 °C for 3 hours.²⁰ By preventing sintering during annealing, the oxidation of the surface plays a key role in the chemical conversion. The experiments just described provide a complete overview of the conversion mechanism of copper to copper vanadates upon reaction with vanadium. Going from sol–gel to NC-seeded solution to solid-state in bulk powders, the formation temperature of



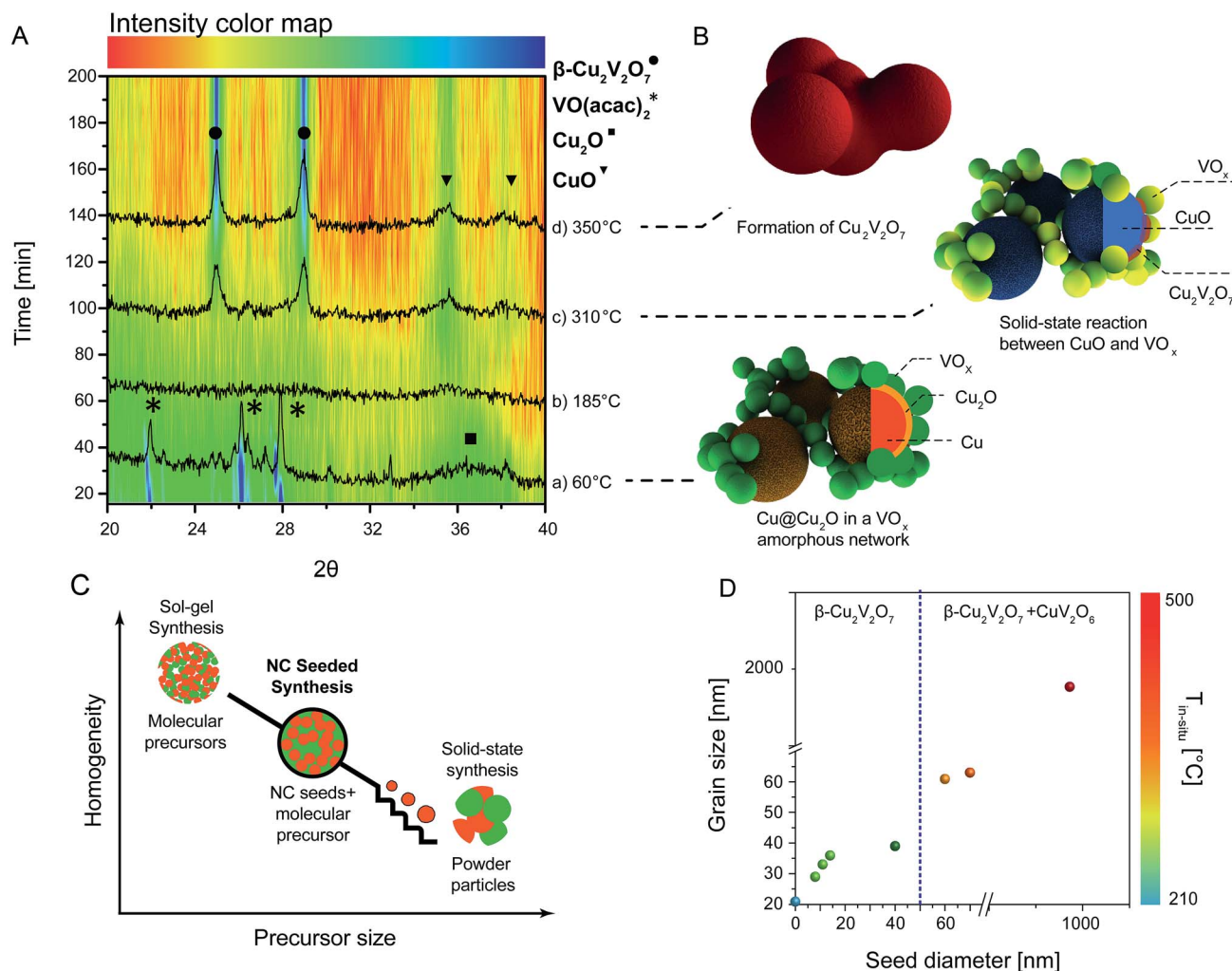


Fig. 4 (A) *In situ* XRD experiments on 6 nm Cu NC seeded synthesis of $\beta\text{-Cu}_2\text{V}_2\text{O}_7$. (B) Schematic drawing of the reaction mechanism. (C) Homogeneity of the precursor solution versus the size of the precursors. The NC-seeded synthesis can be placed between the sol-gel and the solid-state synthesis in terms of homogeneity and diffusion length of the ions. (D) Grain size of $\beta\text{-Cu}_2\text{V}_2\text{O}_7$ versus the Cu seed diameter. For the bulk powders, the seed and grain sizes were assumed to be of the order of micrometers. In the color map $T_{\text{in situ}}$ is the temperature at which the ternary phase was detected during the XRD experiments.

crystalline $\beta\text{-Cu}_2\text{V}_2\text{O}_7$ increases consistently with the increase of diffusion lengths and the decrease of homogeneity in the precursor mixture. If the nucleation step is the reaction limiting step, then the presence of the seeds is expected to lower the crystallization temperature with respect to the sol-gel synthesis.^{2,31} The present results suggest that the conversion rate of this system is predominantly controlled by the growth step and by the ion diffusion rather than by the nucleation step. Regarding the impact of the NC size on the phase purity, the vanadium-rich CuV_2O_6 was formed from both the 60 nm and 70 nm seeds as well as from the bulk powders. CuV_2O_6 is metastable and in the bulk very slowly (170 hours) transformed into the $\beta\text{-Cu}_2\text{V}_2\text{O}_7$ phase, in agreement with the literature.³² Interestingly, this phase was not observed for seeds ≤ 40 nm, which could be due to faster conversion kinetics preventing its isolation and detection given the time resolution of our experiments (10 minutes for each scan). In addition to the phase composition, the NC seed size influences the grain size and the

grain size distribution of the seeded films. As shown by the SEM and XRD analysis (Fig. 2 and Table S1†), smaller seeds result in smaller and more monodisperse grains of $\beta\text{-Cu}_2\text{V}_2\text{O}_7$. Once the nuclei are formed, the grain size of $\beta\text{-Cu}_2\text{V}_2\text{O}_7$ is limited by the distance that the ternary phase can grow before neighboring grains impinge on each other. When smaller NC seeds are used, the higher surface area and homogeneity of the precursor solution provide a higher density of nucleation sites on the surface, which are spatially uniformly distributed, and thus smaller and more monodisperse grains are obtained (Fig. 5). This observation is consistent with much earlier studies on the formation of lead zirconate titanate seeded with a thin layer of lead titanate.³¹ In order to observe this effect, the homogeneity of the NC-seeded precursor solution is key. FTIR analysis of the solution containing the $\text{Cu@Cu}_2\text{O}$ NCs and the $\text{VO}(\text{acac})_2$ in DMF suggests chemical interactions between the NC surface and the vanadium molecular precursor (Fig. S9, Table S2†). This argument also provides an interpretation of previous results.²⁶

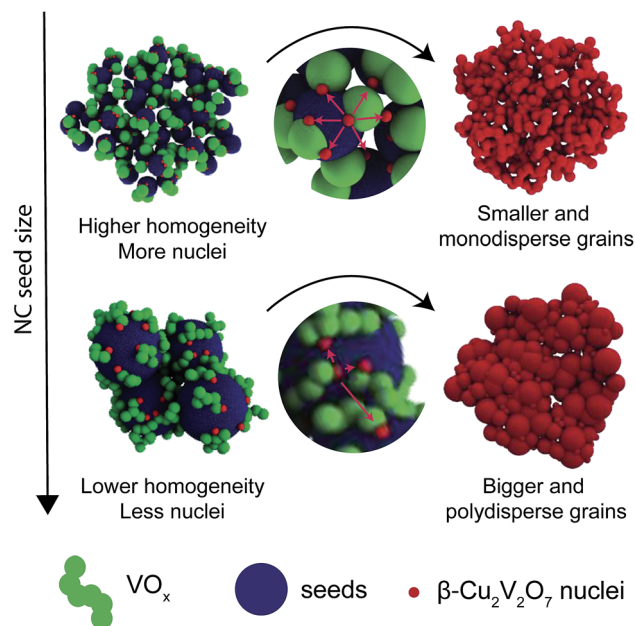


Fig. 5 Schematic illustration of the growth process of β - $\text{Cu}_2\text{V}_2\text{O}_7$.

To cite one example, in the case of BiVO_4 synthesized from the reaction of electrodeposited BiOI platelets and $\text{VO}(\text{acac})_2$, the wettability of seeds by the molecular precursor was found to be a key factor in the formation of a homogenous three dimensional nanoporous network.²⁶

Taking advantage of the tunability afforded by the NC-seeded synthesis, the dependence of the photoelectrochemical (PEC) behavior on the grain size of the β - $\text{Cu}_2\text{V}_2\text{O}_7$ films was investigated. The results are shown in Fig. 6. The optical properties of the films (Fig. S10†) were consistent with literature data for copper vanadates. The photocurrent density (J) versus the applied potential (E) of films synthesized from 6 nm, 11 nm, 14 nm and 40 nm NC seeds were collected in the presence of 0.1 M sodium sulfite (Na_2SO_3), which served as a hole scavenger, under simulated sunlight (Fig. S11†). The fast oxidation kinetics of Na_2SO_3 enables the study of the photoelectrochemical properties of β - $\text{Cu}_2\text{V}_2\text{O}_7$ independently of their slow kinetic properties towards water oxidation.^{18,21} It must be noted that high dark currents were measured in the presence of sodium sulfite (Fig. S11†), which is in agreement with many other literature reports.^{18–20,22,23} While their origin remains to be investigated, they might be indicative of a dark electrochemical reaction occurring between the photoanode surface and the hole scavenger. The incident photon-to-current efficiency (IPCE) and the absorbed photon-to-current efficiency (APCE) follow the trend of the J - E curves and evidence weak photoresponse for wavelengths >600 nm just above the indirect band gap (Fig. S12†). The onset potential around 0.72–0.74 V vs. RHE for all the samples (Fig. S13†) is consistent with the flat band potential of β - $\text{Cu}_2\text{V}_2\text{O}_7$, which is presently reported to lie between 0.68 V and 0.77 V vs. RHE, and with literature results (0.75 V vs. RHE).^{18,23} Fig. 6 plots the net photocurrent density ($J_{\text{net}} = J_{\text{light}} - J_{\text{dark}}$) at 1.23 V vs. RHE versus the grain size and compares these results against the state-of-the-art values for

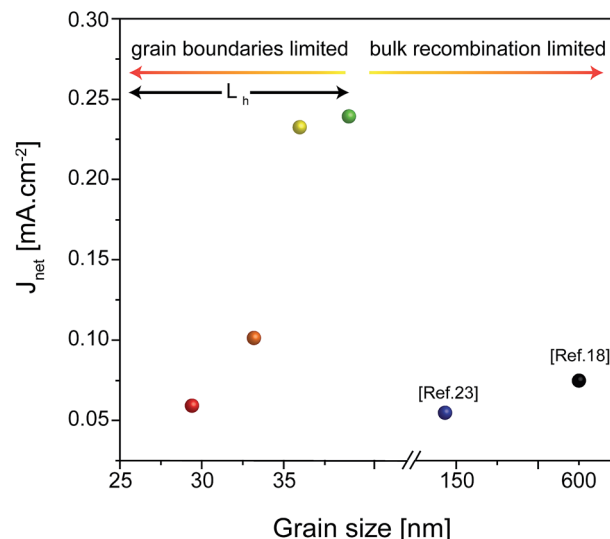


Fig. 6 Net photocurrent density ($J_{\text{light}} - J_{\text{dark}}$) at 1.23 V vs. RHE measured in a 0.1 M sodium borate buffer (pH 8.2) containing 0.1 M Na_2SO_3 as a hole scavenger versus the β - $\text{Cu}_2\text{V}_2\text{O}_7$ grain size. The black and blue colored data points are adapted from Guo *et al.*¹⁸ and Jiang *et al.*²³ L_h indicates the hole diffusion length of β - $\text{Cu}_2\text{V}_2\text{O}_7$.²²

β - $\text{Cu}_2\text{V}_2\text{O}_7$.^{18,23} 1.23 V vs. RHE was chosen as a reference voltage to ease the comparison with literature data. The photocurrent density at 1.23 V vs. RHE increases from 0.05 to 0.23 mA cm^{-2} as the grain size of β - $\text{Cu}_2\text{V}_2\text{O}_7$ increases from 29 nm to 39 nm. In addition to the data points from the literature in Fig. 6, which refer to β - $\text{Cu}_2\text{V}_2\text{O}_7$, numerous other crystalline phases of copper vanadates with grain sizes above 200 nm show lower photocurrent values below 0.1 mA cm^{-2} at 1.23 V vs. RHE in the presence of a hole scavenger in a 9.2 pH borate buffer solution.^{18–20,22,23} In the present work, the highest photocurrent density of 0.23 mA cm^{-2} at 1.23 V vs. RHE is achieved when the grain size is 39 nm which is exactly in the range of the estimated hole diffusion length of copper vanadates (20–40 nm).²² The films with smaller grains exhibit higher densities of grain boundaries, which are deleterious for the transport of electrons to the back contact. As the grain size increases, electronic transport improves, and thus the photocurrent increases up to the grain size of 39 nm. When the grain size becomes bigger than the charge carrier diffusion length, the photoexcited holes do not survive long enough to reach the electrolyte interface thereby drastically reducing the photocurrent density due to bulk recombination. It is interesting to note that the samples containing the interface β - $\text{Cu}_2\text{V}_2\text{O}_7/\text{CuV}_2\text{O}_6$ exhibit a much higher photocurrent (0.43 mA cm^{-2} at 1.23 V vs. RHE) with respect to the pure phase samples. The bulk band gap alignment suggests that charge transfer from β - $\text{Cu}_2\text{V}_2\text{O}_7$ to CuV_2O_6 is possible, and thus this could favor charge extraction thereby mitigating recombination.¹⁸

Fig. 7 shows representative high resolution TEM (HR-TEM) images of the pure phase β - $\text{Cu}_2\text{V}_2\text{O}_7$ and of the mixed phase β - $\text{Cu}_2\text{V}_2\text{O}_7/\text{CuV}_2\text{O}_6$ along with the fast Fourier transforms (FFTs). The morphology of the two samples is very similar and the grain sizes are in the same size range found by XRD. The



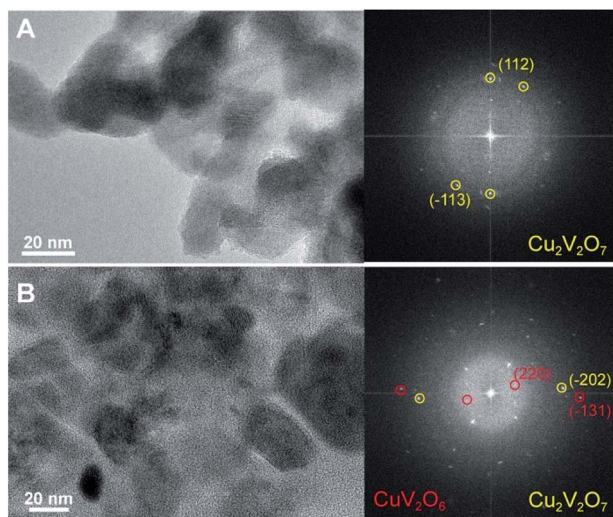


Fig. 7 HR-TEM along with the FFTs of (A) one sample of the pure phase β - $\text{Cu}_2\text{V}_2\text{O}_7$, synthesized from 6 nm Cu NC seeds and (B) one sample of the mixed phase β - $\text{Cu}_2\text{V}_2\text{O}_7/\text{CuV}_2\text{O}_6$, synthesized from 60 nm Cu NC seeds.

FFT analysis, carefully performed on multiple areas of the sample, has evidenced the simultaneous presence of β - $\text{Cu}_2\text{V}_2\text{O}_7$ and CuV_2O_6 with a uniform spatial distribution rather than segregated in different domains. Such an intimate intermixing, which allows for an extended interface area, has been previously demonstrated to be advantageous for maximizing charge separation, and thus photoelectrochemical performance, in heterostructured nanocomposite electrodes.³³

Conclusions

To conclude, our findings reveal the unique opportunities offered by NC-seeded synthesis in materials chemistry. The reaction of Cu NC seeds with the molecular vanadium precursor $\text{VO}(\text{acac})_2$ results in the formation of copper vanadate thin films with tunable grain size. The diameter of the NC seeds plays a key role in determining the grain size and composition of the final reaction product. *In situ* XRD studies reveal the occurrence of a solid-state reaction between the seeds and the vanadium matrix formed during the annealing. The tunability of the grain size afforded by the NC-seeded synthesis offers a mean to study the dependence of the photoelectrochemical performance on the grain size in a range close to the charge carrier diffusion length of β - $\text{Cu}_2\text{V}_2\text{O}_7$ (20–40 nm), something which has been not possible to date. A strong relationship between the grain size and the photocurrent density is revealed, the performance being maximized when the grain size is in the order of the charge carrier diffusion length for this material. Thus, the ability to tune the grain size with high precision is demonstrated to be of paramount importance for the rational design of novel photoabsorbers.

Furthermore, the higher photoelectrochemical performance of the mixed phase samples β - $\text{Cu}_2\text{V}_2\text{O}_7/\text{CuV}_2\text{O}_6$ suggests that nanostructuring plus hetero-structuring might be key to

approach the theoretical performance of copper vanadate photoanodes.^{18,24,33} Future transient absorption measurements will be used to elucidate the correlation between size- and composition-dependent charge carrier dynamics and PEC performance.

Overall, this work demonstrates the potential of NC seeded synthesis to achieve structural and compositional tunability often inaccessible by other methods. This newly defined space in chemical reactivities, which links the more classical sol-gel and solid-state approaches, can be easily explored within the vast family of metal oxides targeting numerous different applications.^{1–12}

Conflicts of interest

There are no conflicts to declare.

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